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November 2015

FDMC4435BZ

P-Channel Power Trench[®] MOSFET -30 V, -18 A, 20 m Ω

Features

- Max $r_{DS(on)}$ = 20 m Ω at V_{GS} = -10 V, I_D = -8.5 A
- Max $r_{DS(on)}$ = 37 m Ω at V_{GS} = -4.5 V, I_D = -6.3 A
- \blacksquare Extended V_{GSS} range (-25 V) for battery applications
- High performance trench technology for extremely low r_{DS(on)}
- High power and current handling capability
- HBM ESD protection level >7 kV typical (Note 4)
- 100% UIL Tested
- Termination is Lead-free and RoHS Compliant

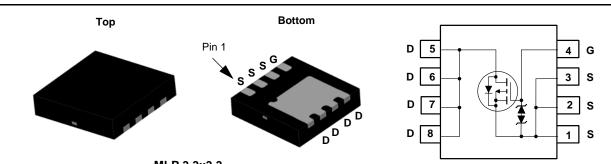


General Description

This P-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench[®] process that has been especially tailored to minimize the on-state resistance. This device is well suited for Power Management and load switching applications common in Notebook Computers and Portable Battery Packs.

Applications

- High side in DC DC Buck Converters
- Notebook battery power management
- Load switch in Notebook



MLP 3.3x3.3

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DS}	Drain to Source Voltage			-30	V
V _{GS}	Gate to Source Voltage			±25	V
	Drain Current -Continuous	T _C = 25 °C		-18	
I _D	-Continuous	T _A = 25 °C	(Note 1a)	-8.5	Α
	-Pulsed			-50	
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	32	mJ
D	Power Dissipation	T _C = 25 °C		31	w
PD	Power Dissipation	T _A = 25 °C	(Note 1a)	2.3	vv
T _J , T _{STG}	Operating and Storage Junction Tempera	ature Range		-55 to +150	°C

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case		4	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	53	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC4435BZ	FDMC4435BZ	MLP 3.3X3.3	13 "	12 mm	3000 units

Symbol	Parameter	Test Cond	litions	Min	Тур	Max	Units
Off Chara	cteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = -250 μA, V _{GS} = 0	0 V	-30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu A$, referen			21		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = -24 V, V _{GS} = 0 V,	T _J = 125 °C			-1 -100	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 25 \text{ V}, \text{ V}_{DS} = 0$	D V			±10	μA
On Chara	cteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250$	Ο μΑ	-1.0	-1.8	-3.0	V
$\Delta V_{GS(th)}$ $\Delta T_{.1}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, referen			-5		mV/°C
		V _{GS} = -10 V, I _D = -8.		14	20		
r	Static Drain to Source On Resistance	$V_{GS} = -4.5 \text{ V}, \ I_D = -6.3 \text{ A}$ $V_{GS} = -10 \text{ V}, \ I_D = -8.5 \text{ A},$ $T_J = 125 \text{ °C}$			21	37	mΩ
r _{DS(on)}				20	29	11132	
9 _{FS}	Forward Transconductance	$V_{DD} = -5 V, I_D = -8.5 A$			25		S
•	Characteristics	1			4505	0040	- 5
C _{iss}	Input Capacitance Output Capacitance	V _{DS} = -15 V, V _{GS} = 0 V, -f = 1 MHz			1535 310	2040 410	pF pF
C _{oss} C _{rss}	Reverse Transfer Capacitance				280	410	pF
R _q	Gate Resistance	f = 1 MHz			4	420	Ω
0	Characteristics						
t _{d(on)}	Turn-On Delay Time				10	20	ns
t _r	Rise Time	V _{DD} = -15 V, I _D = -8.5 A, V _{GS} = -10 V, R _{GEN} = 6 Ω			9	18	ns
t _{d(off)}	Turn-Off Delay Time				35	56	ns
t _f	Fall Time	-			19	34	ns
Qg	Total Gate Charge	$V_{GS}=0V$ to -10V			38	53	nC
Qg	Total Gate Charge	V_{GS} = 0 V to -4.5 V	V _{DD} = -15 V,		20	28	nC
Q _{gs}	Gate to Source Charge	$V_{GS} = 0 \text{ V to } -4.5 \text{ V}$ $V_{DD} = -15 \text{ V},$ $I_D = -8.5 \text{ A}$			4.3		nC
Q _{gd}	Gate to Drain "Miller" Charge				11		nC
Drain-Soເ	Irce Diode Characteristics						
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = -8.5A$ $V_{GS} = 0 V, I_S = -1.9 A$	(Note 2) (Note 2)		0.86 0.74	1.5 1.2	V
t _{rr}	Reverse Recovery Time				26	40	ns
Q _{rr}	Reverse Recovery Charge	I _F = -8.5 A, di/dt = 100 A/μs			12	20	nC
NOTES: I. R _{θJA} is determ the user's boai	ined with the device mounted on a 1 in ² pad 2 oz copper rd design.	pad on a 1.5 x 1.5 in. board of	FR-4 material. $R_{\theta JC}$ is	guaranteed	by design wh	iile R _{θCA} is de	etermined b

4. The diode connected between the gate and source servers only as protection against ESD. No gate overvoltage rating is implied. ©2010 Fairchild Semiconductor Corporation FDMC4435BZ Rev.2.5

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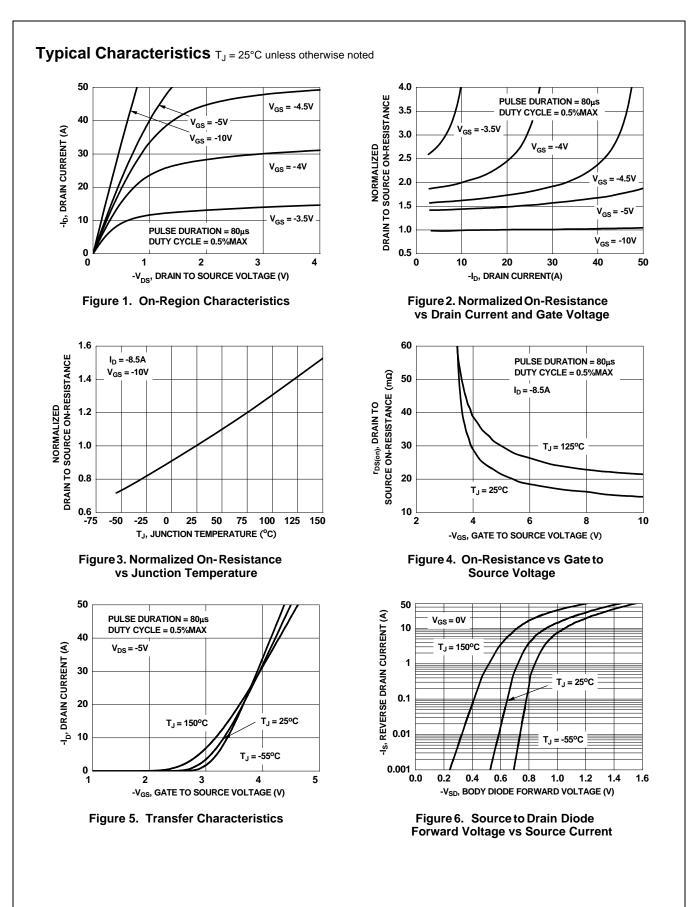
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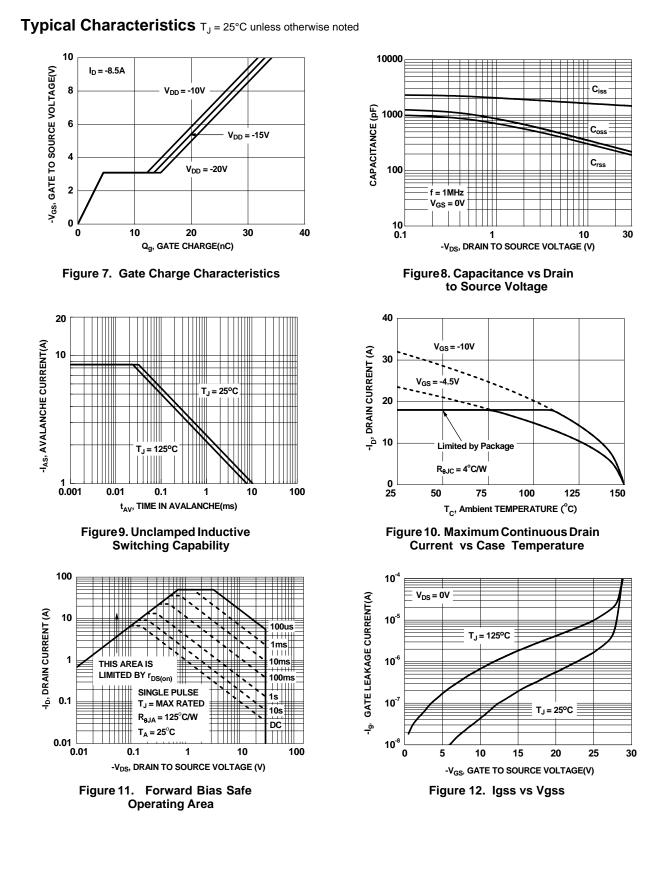
3. Starting T_J = 25°C; P-ch: L = 1mH, I_{AS} = -8A, V_{DD} = -27V, V_{GS} = -10V.

2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0 %.

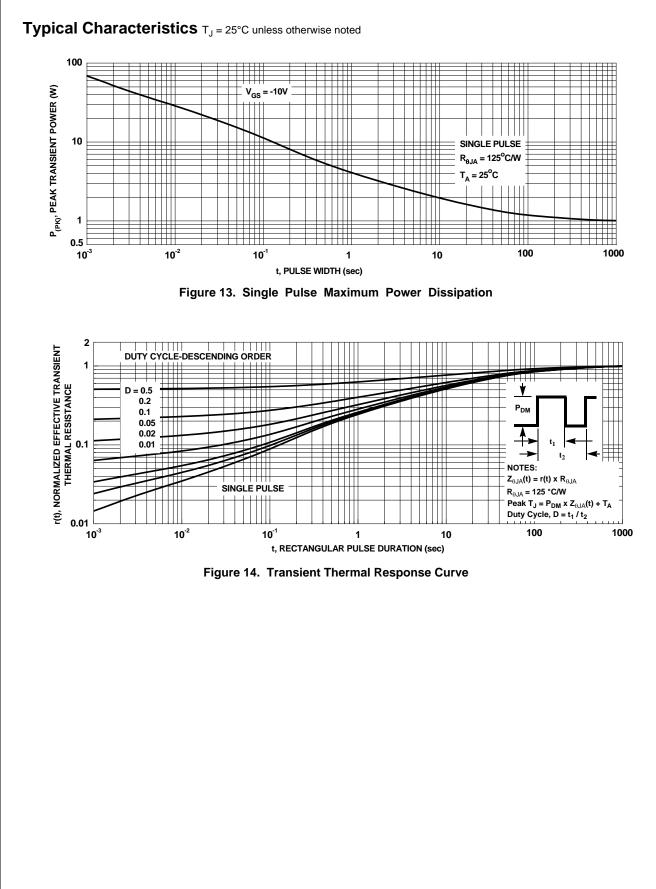
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b.125 °C/W when mounted on a minimum pad of 2 oz copper

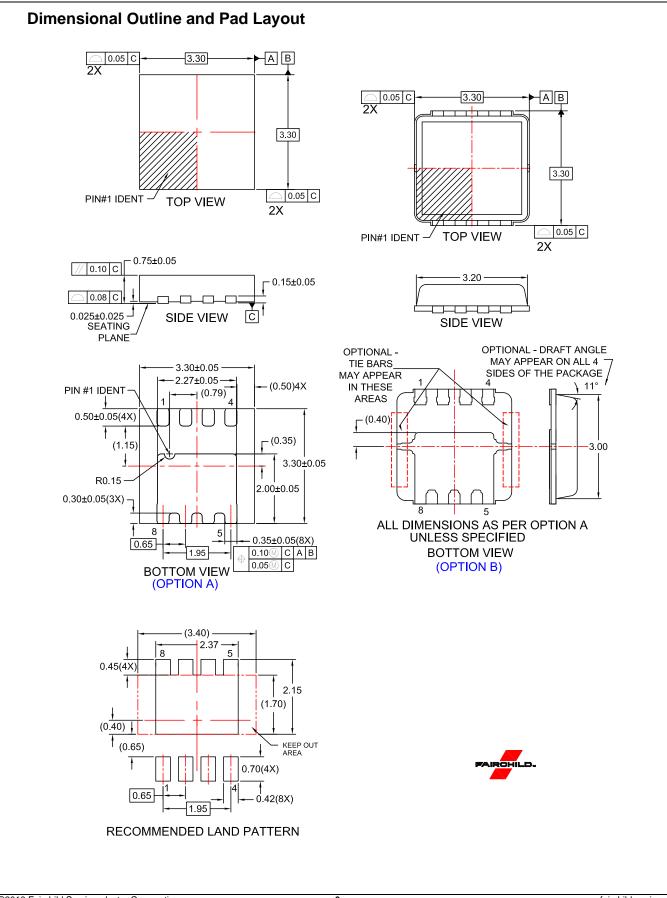




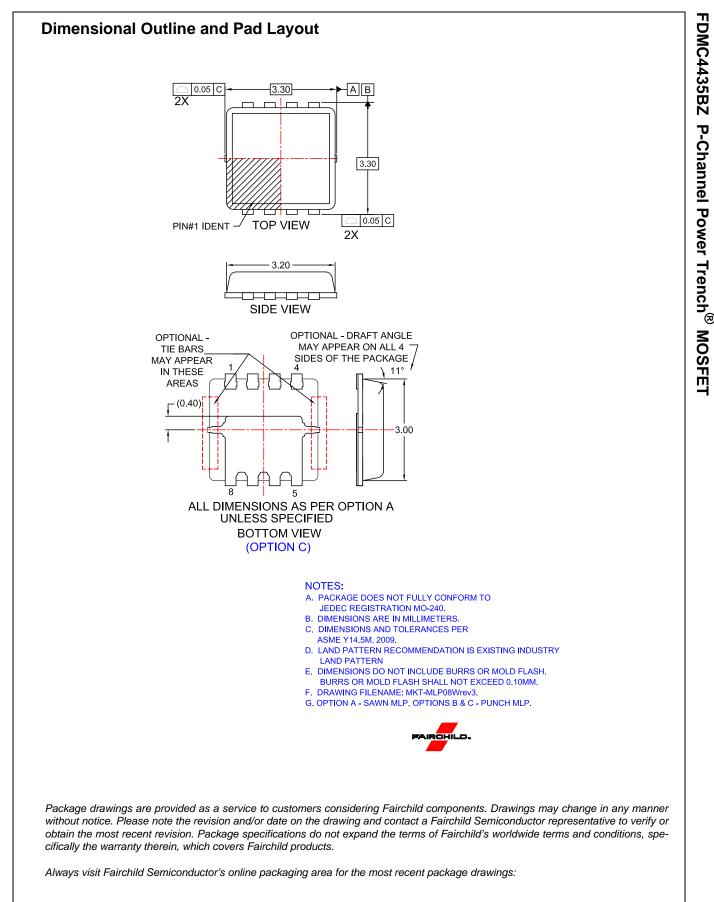
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